DESCRIPTION

The S8050 is available in SOT-23 package.

FEATURES

- High collector current (I_C = 500mA)
- Excellent h_{FE} Linearity
- High total power dissipation. (P_C = 300mW)
- Available in SOT-23 package

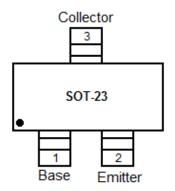
ORDERING INFORMATION

Package Type	Part Number		
SOT-23	S8050		
Note	SPQ: 3,000pcs/Reel		
AiT provides all RoHS Compliant Products			

APPLICATION

• High Collector Current

PIN DESCRIPTION



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ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise specified

TA = 25 C, unless otherwise specified	
V _{CBO} , Collector-Base Voltage	40V
V _{CEO} , Collector-Emitter Voltage	25V
V _{EBO} , Emitter-Base Voltage	5V
Ic, Collector Current-Continuous	500mA
Pc, Collector Dissipation	300mW
T _J , T _{STG} , Junction and Storage Temperature	-55°C~150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

T_A = 25°C unless otherwise noted

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-Base Breakdown Voltage	V _{(BR)CBO}	I _C =100μA, I _E =0	40	-	-	V
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C =0.1mA, I _B =0	25	-	-	V
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	I _E =100μA, I _C =0	5	-	-	V
Collector Cut-off Current	Ісво	V _{CB} =40V, I _E =0	-	-	0.1	μΑ
Collector Cut-off Current	I _{CEO}	V _{CE} =20V, I _B =0	-	-	0.1	μΑ
Emitter Cut-off Current	I _{EBO}	V _{EB} =5V, I _C =0	-	-	0.1	μΑ
DC Current Gain	h _{FE}	V _{CE} =1V, I _C =50mA	200	-	350	
		V _{CE} =1V, I _C =500mA	50	-	-	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C =500mA, I _B =50mA	-	-	0.6	V
Base-Emitter Saturation Voltage	V _{BE(sat)}	I _C =500mA, I _B =50mA	-	-	1.2	V
Transition Frequency	f⊤	V _{CE} =6V, I _C =20mA,	150		-	MHz
		f=30MHz		-		IVIITZ

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TYPICAL CHARACTERISTICS

Figure 1. Static Characteristic

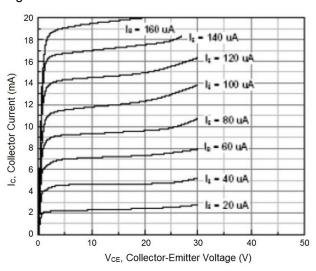


Figure 3. Base-Emitter Saturation Voltage Collector –Emitter Saturation Voltage

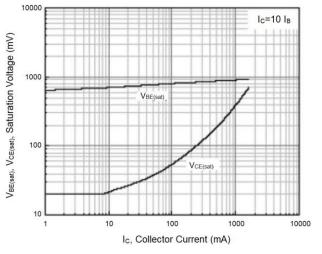


Figure 2. DC Current Gain

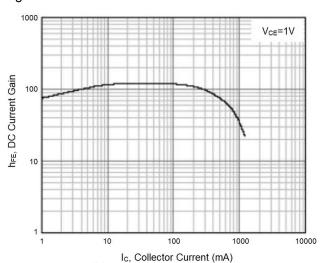
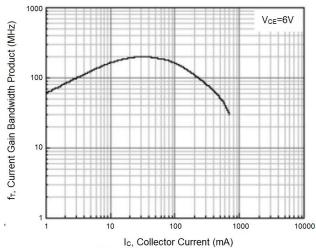


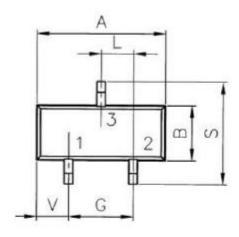
Figure 4. Current Gain Bandwidth Product

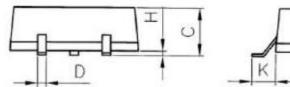


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PACKAGE INFORMATION

Dimension in SOT-23 Package (Unit: mm)







Symbol	MIN	MAX
Α	2.80	3.04
В	1.20	1.40
С	0.89	1.13
D	0.30	0.50
G	1.78	2.04
Н	0.01	0.10
J	0.08	0.18
K	0.45	0.60
L	0.89	1.02
S	2.10	2.50
V	0.42	0.60

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IMPORTANT NOTICE

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